DY2M5Z0C0L1

For bidirectional ESD protection and transient voltage suppressor

■ Features

- IEC 61000-4-2 (ESD) ±15 kV (Contact and Air)
- IEC 61000-4-5 (Lightning) 1.9 A (8/20 μs)
- · Low leak current
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

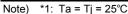
■ Marking Symbol:

■ Packaging

Embossed type (Thermo-compression sealing): 20 000 pcs / reel (standard)

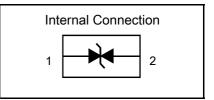
■ Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
Total Power Dissipation *1, 2	PT	ı	150	mW
Electrostatic Discharge *1,3	ESD	ı	±15	kV
Peak Pulse Power *1, 4	Ppp	ı	20	W
Peak Pulse Current *1, 4	lpp	ı	1.9	Α
Operating Junction Temperature *5	Tj	ı	150	°C
Ambient Temperature	Та	-40	150	°C
Storage Temperature	Tstg	-55	150	°C



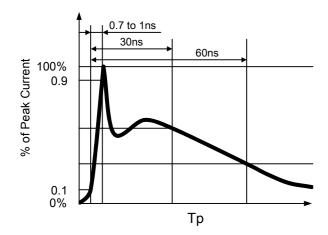
- *2: Device mounted on a FR4 PCB (25.4mm×25.4mm, 1mm thick), copper wiring (27.6mm² area, 36µm thick).
- *3: Test method: IEC61000-4-2 (C = 150 pF , R = 330 Ω , Contact and Air discharge: 10 times)
- *4: Test method: IEC61000-4-5 (Tp = 8/20 μs , Unrepeated)
- *5: Power derating is necessary so that Tj < 150°C.

1. Anode 2. Anode Panasonic DCSP0402010-N2 JEITA — Code —



(IEC61000-4-2 Pulse)

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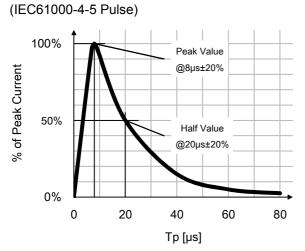


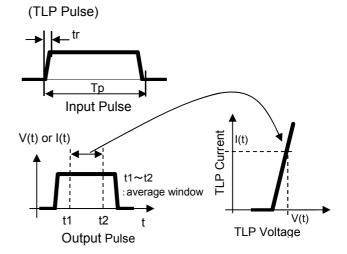
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TVS Diode

DY2M5Z0C0L1

Panasonic



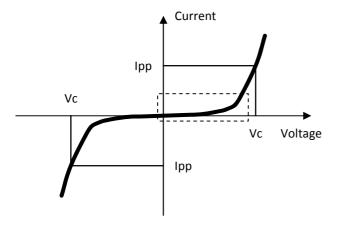


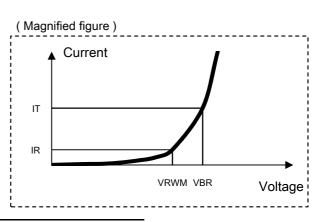
■ Electrical Characteristics Ta = 25°C ± 3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Stand-off Voltage	VRWM	-			5.0	V
Reverse Breakdown Voltage *1	VBR	IT = 0.1 mA	7.0	7.5	8.0	V
Reverse Breakdown Voltage *1	VBR	IT = 5 mA	7.0	7.6	8.0	V
Reverse Leakage Current	IR	VR = 5 V			50	nA
Clamping Voltage *2	Vc	lpp = 1.9 A, Tp = 8/20 μs		10.6	12.7	V
Clamping Voltage *3	Vc-TLP	Ipp = 8 A		12.0		V
Clamping Voltage *3	Vc-TLP	Ipp = 16 A		16.0		V
Terminal Capacitance	Ct	VR = 0 V, f = 1 MHz		6.0		pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031measuring methods for diodes.

- 2. Absolute frequency of input and output is 5 MHz.
- 3. *1: VBR guaranteed 20 ms after current flow.
 - *2: conditions: 8/20 µs Pulse Waveform
 - *3: conditions : TLP parameter $Z = 50~\Omega$, Tp = 100 ns , tr = 0.2ns , average window t1 = 54.4ns , t2 = 94.4ns

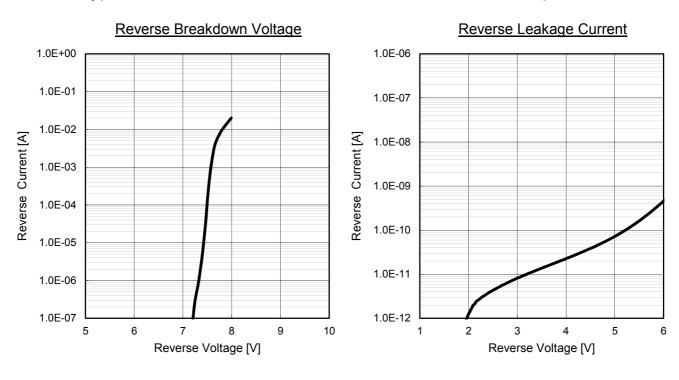


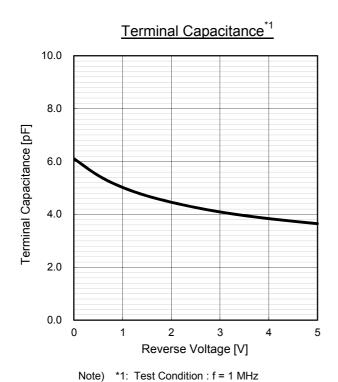


Symbol	Parameter	
lpp	Peak Pulse Current	
Vc	Clamping Voltage @ Ipp	
IR	Reverse Leakage Current @ VRWM	
VRWM	Reverse Stand-off Voltage	
ΙΤ	Test Current	
VBR	VBR Breakdown Voltage @ IT	
	_	

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Typical Characteristics at Ta = 25°C, unless otherwise specified



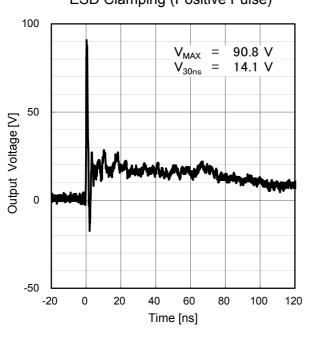


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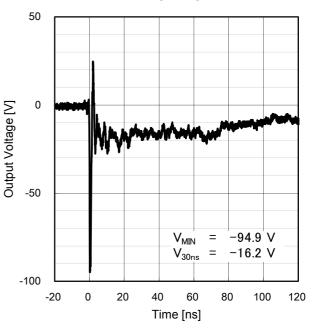
Typical Characteristics at Ta = 25°C, unless otherwise specified





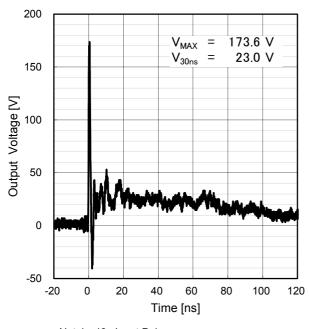
Note) *1: Input Pulse : IEC61000-4-2 / Contact / + 8 kV

ESD Clamping (Negative Pulse)*2



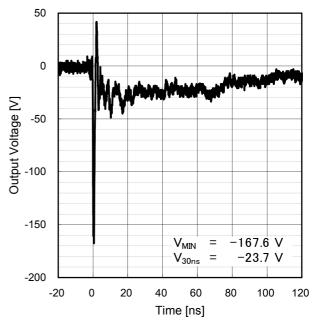
Note) *2: Input Pulse : IEC61000-4-2 / Contact / - 8 kV

ESD Clamping (Positive Pulse)*3



Note) *3: Input Pulse : IEC61000-4-2 / Contact / + 15 kV

ESD Clamping (Negative Pulse)*4

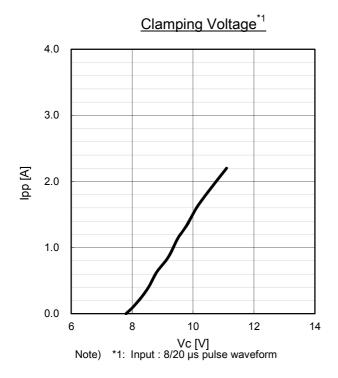


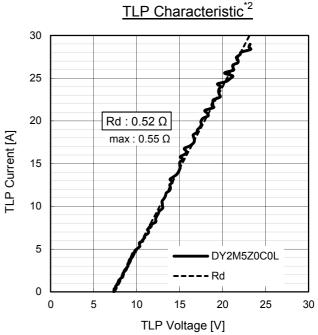
Note) *4: Input Pulse : IEC61000-4-2 / Contact / - 15 kV

TVS Diode

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Typical Characteristics at Ta = 25°C, unless otherwise specified



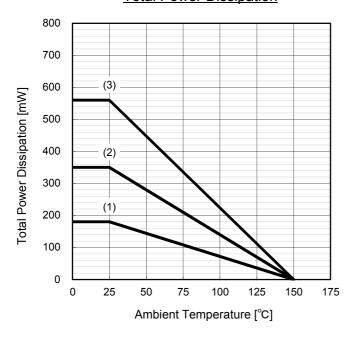


Note) *2: Input Pulse: Tp = 100ns, tr = 0.2ns, average window t1 = 54.4ns, t2 = 94.4ns

Extraction of Rd using least squares fit of TLP characteristic between Ipp = 10 A and Ipp = 25 A.

Rd: Dynamic resistance

Total Power Dissipation

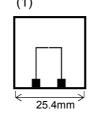


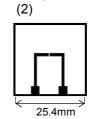
(Evaluation Board Condition °)

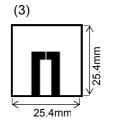
	PCB Size	Copper Wiring		
	PCB Thickness	Thickness	Area	
(1)	25.4 mm ×25.4 mm		27.6 mm ²	
(2)		36 µm thick	50.7 mm ²	
(3)	1 mm thick		108.0 mm ²	

Note) *3: FR4 PCB

(Evaluation Board Outline)





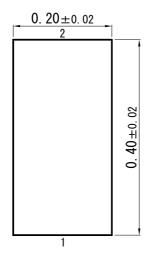


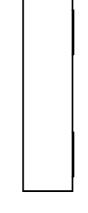
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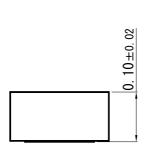
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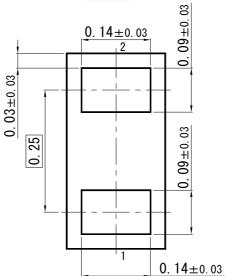
DCSP0402010-N2

Unit: mm

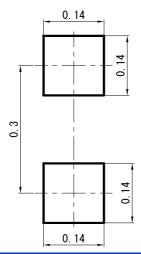








■ Land Pattern (Reference) (Unit: mm)



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